



SBRT05U20LPQ

0.5A TrenchSBR TRENCH SUPER BARRIER RECTIFIER

Product Summary (@ T_A = +25°C)

V _{RRM} (V)	I _O (A)	V _F Max (V)	I _R Max (mA)
20	0.5	0.39	0.05

Description

Packaged in the compact DFN1006 package, the Trench SBR SBRT05U20LP provides ultra-low forward voltage drop (V_F) and provides excellent low reverse leakage stability at high temperatures. It is ideal for use as a rectification, freewheeling or polarity protection diode.

Applications

- SMPS
- Freewheeling Diodes
- Reverse Polarity Protection
- DC-DC Converters
- General Switching Applications

Features and Benefits

- Ultra-Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented SBR[®] (Super Barrier Rectifier) Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: X1-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Dot
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)

X1-DFN1006-2







Bottom View

Ordering Information (Note 5)

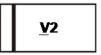
Part Number	Case	Packaging	
SBRT05U20LPQ-7B	X1-DFN1006-2	10.000/Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

X1-DFN1006-2



V2 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	20	V
RMS Reverse Voltage	V _{R(RMS)}	14	V
Average Rectified Output Current (See Figure 4)	lo	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	10	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 6)	$R_{\theta JA}$	236	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

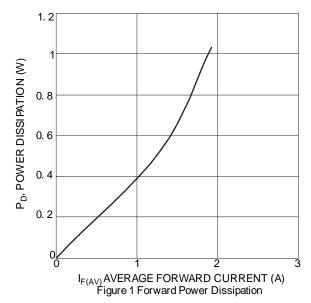
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

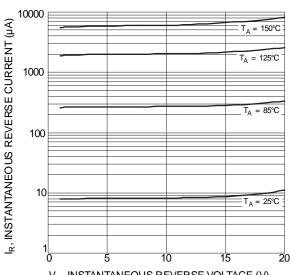
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop	VF	 - 	0.28 0.30 0.35	0.32 0.34 0.39	V	$I_F = 0.1A$, $T_J = +25$ °C $I_F = 0.2A$, $T_J = +25$ °C $I_F = 0.5A$, $T_J = +25$ °C
Leakage Current (Note 7)	I _R	_	11 2.5	50 10	μA mA	V _R = 20V, T _J = +25°C V _R = 20V, T _J = +125°C
Total Capacitance	C _T	_	14	_	pF	f = 1MHz, V _R = 20V
Reverse Recovery Time	t _{RR}	-	15 6	-	ns	$\begin{split} I_F = & I_R = 10 \text{mA}, \ I_{R(REC)} = 1 \text{mA}, \\ R_L = & 100 \Omega \\ I_F = & 500 \text{mA}, \ di/dt = 600 \text{A/}\mu\text{s}, \\ V_R = & 10 \text{V} \end{split}$

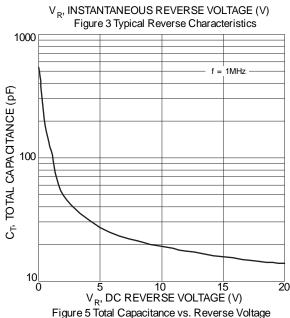
Notes:

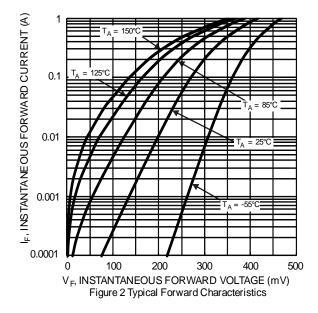
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 7. Short duration pulse test used to minimize self-heating effect.

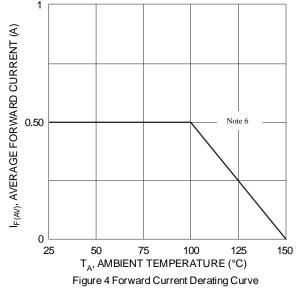










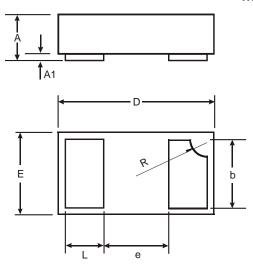




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-2

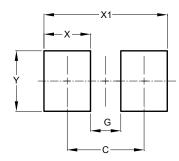


X1-DFN1006-2				
Dim	Min	Max	Тур	
Α	0.47	0.53	0.50	
A1	0	0.05	0.03	
b	0.45	0.55	0.50	
D	0.95	1.075	1.00	
Е	0.55	0.675	0.60	
е	-	_	0.40	
L	0.20	0.30	0.25	
R	0.05	0.15	0.10	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-2



Dimensions	Value (in mm)
С	0.70
G	0.30
Х	0.40
X1	1.10
Υ	0.70



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